# SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

### **General Description**

The MAX4475–MAX4478/MAX4488/MAX4489 wideband, low-noise, low-distortion operational amplifiers offer rail-to-rail outputs and single-supply operation down to 2.7V. They draw 2.2mA of quiescent supply current per amplifier while featuring ultra-low distortion (0.0002% THD+N), as well as low input voltage-noise density (4.5nV/ $\sqrt{\rm Hz}$ ) and low input current-noise density (0.5fA/ $\sqrt{\rm Hz}$ ). These features make the devices an ideal choice for applications that require low distortion and/or low noise.

For power conservation, the MAX4475/MAX4488 offer a low-power shutdown mode that reduces supply current to 0.01µA and places the amplifiers' outputs into a high-impedance state. These amplifiers have outputs which swing rail-to-rail and their input common-mode voltage range includes ground. The MAX4475–MAX4478 are unity-gain stable with a gain-bandwidth product of 10MHz. The MAX4488/4489 are internally compensated for gains of +5V/V or greater with a gain-bandwidth product of 42MHz. The single MAX4475/MAX4476/MAX4488 are available in space-saving, 6-pin SOT23 and TDFN packages.

### **Applications**

- ADC Buffers
- DAC Output Amplifiers
- Low-Noise Microphone/Preamplifiers
- Digital Scales
- Strain Gauges/Sensor Amplifiers
- Medical Instrumentation
- Automotive

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#### **Features**

- Low Input Voltage-Noise Density: 4.5nV/√Hz
- Low Input Current-Noise Density: 0.5fA/√Hz
- Low Distortion: 0.0002% THD+N (1kΩ load)
- Single-Supply Operation from +2.7V to +5.5V
- Input Common-Mode Voltage Range Includes Ground
- Rail-to-Rail Output Swings with a  $1k\Omega$  Load
- 10MHz GBW Product, Unity-Gain Stable (MAX4475–MAX4478)
- 42MHz GBW Product, Stable with AV ≥ +5V/V (MAX4488/MAX4489)
- Excellent DC Characteristics

 $V_{OS} = 70 \mu V$ 

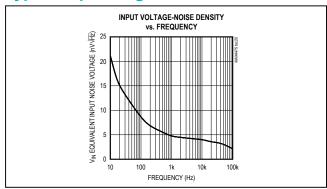
 $I_{BIAS} = 1pA$ 

Large-Signal Voltage Gain = 120dB

- Low-Power Shutdown Mode:
- Reduces Supply Current to 0.01µA
- Places Output in High-Impedance State
- Available in Space-Saving SOT23, TDFN, μMAX®, and TSSOP Packages
- AEC-Q100 Qualified, Refer to Ordering Information for the List of /V Parts

Ordering Information at end of data sheet.

### **Typical Operating Characteristic**



Pin Configurations and Typical Operating Circuit appear at end of data sheet.



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## **Absolute Maximum Ratings**

Power-Supply Voltage (V <sub>DD</sub> to V <sub>SS</sub> )0.3V to +6.0V
Analog Input Voltage (IN_+, IN).(V <sub>SS</sub> - 0.3V) to (V <sub>DD</sub> + 0.3V
SHDN Input Voltage(V <sub>SS</sub> - 0.3V) to +6.0\
Output Short-Circuit Duration to Either Supply Continuous
Continuous Input Current (IN+, IN-)±10m/
Continuous Power Dissipation (T <sub>A</sub> = +70°C)
6-Pin SOT23 (derate 5.4mW/°C above +70°C)431.3mW
6-Pin TDFN (derate 18.2mW/°C above 70°C)1454mW
8-Pin µMAX (derate 4.5mW/°C above +70°C)362mV

8-Pin SO (derate 5.88mW/°C above +70°C)	.471mW
14-Pin SO (derate 8.33mW/°C above +70°C)	.667mW
14-Pin TSSOP (derate 9.1mW/°C above +70°C)	.727mW
Operating Temperature Range40°C to	+125°C
Junction Temperature	+150°C
Storage Temperature Range65°C to	+150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **Package Information**

### SOT23-6

PACKAGE CODE	U6F+6
Outline Number	21-0058
Land Pattern Number	90-0175
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	185.5°C/W
Junction to Case (θ <sub>JC</sub> )	75°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	134.4°C/W
Junction to Case (θ <sub>JC</sub> )	39°C/W

### µMAX-8

PACKAGE CODE	U8+4				
Outline Number	21-0036				
Land Pattern Number	90-0092				
Thermal Resistance, Multi-Layer Board					
Junction to Ambient (θ <sub>JA</sub> )	206°C/W				
Junction to Case (θ <sub>JC</sub> )	42				

### µMAX-8

PACKAGE CODE	U8+1
Outline Number	21-0036
Land Pattern Number	90-0092
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	221°C/W
Junction to Case $(\theta_{JC})$	42°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	206°C/W
Junction to Case $(\theta_{JC})$	42°C/W

## **Package Information (continued)**

## TSSOP-14

PACKAGE CODE	U14+2
Outline Number	<u>21-0066</u>
Land Pattern Number	90-0113
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	110°C/W
Junction to Case (θ <sub>JC</sub> )	30°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	100.4°C/W
Junction to Case (θ <sub>JC</sub> )	30°C/W

### **SO-8**

PACKAGE CODE	S8+4
Outline Number	21-0041
Land Pattern Number	90-0096
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	170°C/W
Junction to Case $(\theta_{JC})$	40
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	132°C/W
Junction to Case (θ <sub>JC</sub> )	38

### **SO-14**

PACKAGE CODE	S14+4
Outline Number	21-0041
Land Pattern Number	90-0112
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	120°C/W
Junction to Case $(\theta_{JC})$	37°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	84°C/W
Junction to Case (θ <sub>JC</sub> )	34°C/W

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## **Package Information (continued)**

### TDFN-6

PACKAGE CODE	T633+2
Outline Number	21-0137
Land Pattern Number	90-0058
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	55°C/W
Junction to Case (θ <sub>JC</sub> )	9°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ <sub>JA</sub> )	42°C/W
Junction to Case (θ <sub>JC</sub> )	9°C/W

For the latest package outline information and land patterns (footprints), go to <a href="www.maximintegrated.com/packages">www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

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### **DC Electrical Characteristics**

 $(V_{DD}$  = +5V,  $V_{SS}$  = 0V,  $V_{CM}$  = 0V,  $V_{OUT}$  =  $V_{DD}/2$ ,  $R_L$  tied to  $V_{DD}/2$ , SHDN =  $V_{DD}$ ,  $T_A$  = -40°C to +125°C, unless otherwise noted. Typical values are at  $T_A$  = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	UNITS	
Supply Voltage Range	V <sub>DD</sub>	(Note 3)	(Note 3)		2.7		5.5	V	
		Normal mode $ \frac{V_{DD} = 3V}{V_{DD} = 5V} $		V <sub>DD</sub> = 3V		2.2			
Quiescent Supply Current Per Amplifier	I <sub>D</sub>				2.5	4.4	mA		
Amplinei		Shutdown mode	(SHDN =	V <sub>SS</sub> ) (Note 2)		0.01	1.0	μA	
1 1 000 1 1 1 1 1	.,	T <sub>A</sub> = +25°C				±70	±350	μV	
Input Offset Voltage	Vos	$T_A = -40^{\circ}C \text{ to } +12^{\circ}$	25°C				±750		
Input Offset Voltage Tempco	TC <sub>VOS</sub>					±0.3	±6	μV/°C	
Input Bias Current	I <sub>B</sub>	(Note 4)				±1	±150	pА	
Input Offset Current	los	(Note 4)				±1	±150	pА	
Differential Input Resistance	R <sub>IN</sub>					1000		GΩ	
Input Common-Mode Voltage		Guaranteed by	T <sub>A</sub> = +	25°C	-0.2		V <sub>DD</sub> - 1.6	\ ,.	
Range	V <sub>CM</sub>	CMRR Test	T <sub>A</sub> = -4	10°C to +125°C	-0.1		V <sub>DD</sub> - 1.7	V	
	CMRR	$(V_{SS} - 0.2V) \le V_{CM} \le (V_{DD} - 1.6V)$	T <sub>A</sub> = +	T <sub>A</sub> = +25°C		115			
Common-Mode Rejection Ratio	(V <sub>SS</sub> - 0.1V) ≤		90			dB			
Power-Supply Rejection Ratio	PSRR	V <sub>DD</sub> = 2.7 to 5.5\	V <sub>DD</sub> = 2.7 to 5.5V			120		dB	
		$R_L = 10k\Omega$ to $V_{DD}/2$ ; $V_{OUT} = 100mV$ to $(V_{DD} - 125mV)$			90	120			
Large-Signal Voltage Gain	A <sub>VOL</sub>	$R_L = 1k\Omega$ to $V_{DD}$ $V_{OUT} = 200$ mV to		250mV)	85	110		dB	
		$R_L = 500\Omega$ to $V_D$ $V_{OUT} = 350$ mV to	<sub>D</sub> /2; o (V <sub>DD</sub> -	500mV)	85	110			
		V <sub>IN+</sub> - V <sub>IN-</sub>   ≥ 10	mV,	V <sub>DD</sub> - V <sub>OH</sub>		10	45		
		$R_L = 10k\Omega$ to $V_{DI}$	101 0 1 1 1 10	V <sub>OL</sub> - V <sub>SS</sub>		10	40		
Output Valtage Suing	\ \/	V <sub>IN+</sub> - V <sub>IN-</sub>   ≥ 10	mV,	V <sub>DD</sub> - V <sub>OH</sub>		80	200	\ /	
Output Voltage Swing	V <sub>OUT</sub>	$R_L = 1k\Omega$ to $V_{DD}$	/2	V <sub>OL</sub> - V <sub>SS</sub>		50	150	mV	
		V <sub>IN+</sub> - V <sub>IN-</sub>   ≥ 10	mV,	V <sub>DD</sub> - V <sub>OH</sub>		100	300		
		D " 500" V '0'		V <sub>OL</sub> - V <sub>SS</sub>		80	250		
Output Short-Circuit Current	I <sub>SC</sub>					48		mA	
Output Leakage Current	I <sub>LEAK</sub>	Shutdown mode (SHDN = V <sub>SS</sub> ), V <sub>OUT</sub> = V <sub>SS</sub> to V <sub>DD</sub>			±0.001	±1.0	μΑ		
SHDN Logic-Low	V <sub>IL</sub>						0.3 x V <sub>DD</sub>	V	
SHDN Logic-High	V <sub>IH</sub>				0.7 x V <sub>DD</sub>			V	
SHDN Input Current		SHDN = V <sub>SS</sub> to \	/ <sub>DD</sub>			0.01	1	μA	
Input Capacitance	C <sub>IN</sub>					10		pF	

### **AC Electrical Characteristics**

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \overline{SHDN} = V_{DD}, T_A = +25^{\circ}C.)$ 

PARAMETER	SYMBOL	CONDITI	ONS	MIN TYP	MAX	UNITS	
Online Down deviable Down deviat	CDMD	MAX4475-MAX4478	A <sub>V</sub> = +1V/V	10		MHz	
Gain-Bandwidth Product	GBWP	MAX4488/MAX4489	A <sub>V</sub> = +5V/V	42		IVITZ	
Slew Rate	SR	MAX4475-MAX4478	A <sub>V</sub> = +1V/V	3		V/µs	
Slew Rate	SK	MAX4488/MAX4489	A <sub>V</sub> = +5V/V	10		V/μS	
Full-Power Bandwidth (Note 5)		MAX4475-MAX4478	A <sub>V</sub> = +1V/V	0.4		MHz	
Tull-Fower Ballumuti (Note 3)		MAX4488/MAX4489	A <sub>V</sub> = +5V/V	1.25		IVII IZ	
Peak-to-Peak Input Noise Voltage	e <sub>n(P-P)</sub>	f = 0.1Hz to 10Hz		260	nVp₋p		
		f = 10Hz		21			
Input Voltage-Noise Density	e <sub>n</sub>	f = 1kHz		4.5		nV/√Hz	
		f = 30kHz		3.5			
Input Current-Noise Density	i <sub>n</sub>	f = 1kHz		0.5		fA/√Hz	
		V <sub>OUT</sub> = 2V <sub>P-P</sub> , A <sub>V</sub> = +1V/V	f = 1kHz	0.0002			
		(MAX4475-MAX4478), $R_L = 10k\Omega$ to GND	f = 20kHz	0.0007			
Total Harmonic Distortion Plus	THD + N	$V_{OUT} = 2V_{P-P},$ $A_V = +1V/V$ (MAX4475–MAX4478), $R_L = 1k\Omega$ to GND	f = 1kHz	0.0002		0/	
Noise (Note 6)			f = 20kHz	0.001		%	
		$V_{OUT} = 2V_{P-P},$ $A_V = +5V/V \text{ (MAX4488/MAX4489)},$ $R_L = 10k\Omega \text{ to GND}$	f = 1kHz	0.0004			
			f = 20kHz	0.0006			
Total Harmonic Distortion Plus		V <sub>OUT</sub> = 2V <sub>P-P</sub> , A <sub>V</sub> = +5V/V	f = 1kHz	0.0005			
Noise (Note 6)	THD + N	(MAX4488/MAX4489), $R_L = 1k\Omega$ to GND	f = 20kHz	0.008		%	
Capacitive-Load Stability		No sustained oscillations	No sustained oscillations			pF	
Gain Margin	GM			12		dB	
Phase Margin		MAX4475–MAX4478, A <sub>V</sub> = +1V/V		70		_	
	ΦМ	MAX4488/MAX4489, A <sub>V</sub>	80		degrees		
Settling Time		To 0.01%, V <sub>OUT</sub> = 2V st	2		μs		
Delay Time to Shutdown	t <sub>SH</sub>	, 1001 21 00		1.5		μs	
Enable Delay Time from Shutdown		V <sub>OUT</sub> = 2.5V, V <sub>OUT</sub> sett	les to 0.1%	1.0		·	
	t <sub>EN</sub>		13		μs		
Power-Up Delay Time		V <sub>DD</sub> = 0 to 5V step, V <sub>OUT</sub> stable to 0.1%				μs	

**Note 1:** All devices are 100% tested at  $T_A = +25$ °C. Limits over temperature are guaranteed by design.

Note 2: SHDN is available on the MAX4475/MAX4488 only.

Note 3: Guaranteed by the PSRR test.

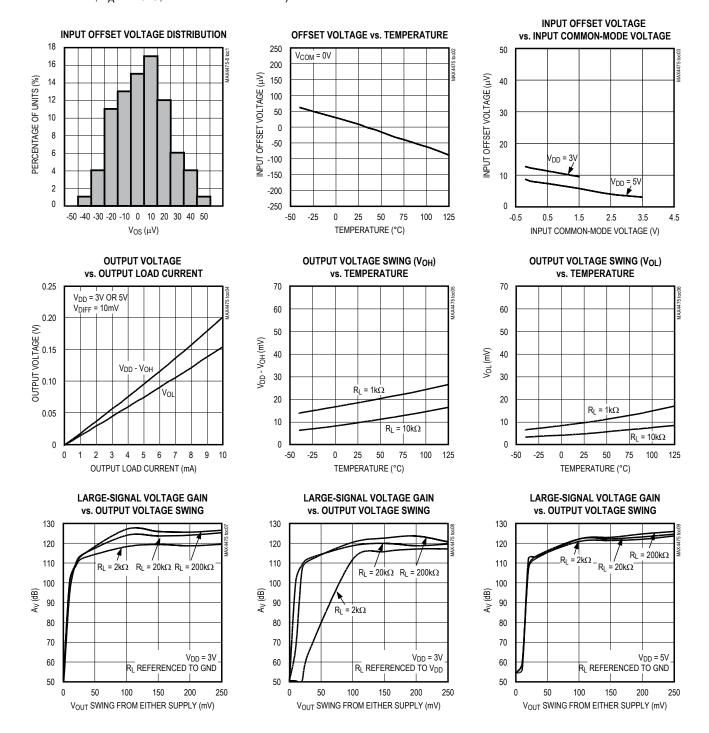
Note 4: Guaranteed by design.

Note 5: Full-power bandwidth for unity-gain stable devices (MAX4475–MAX4478) is measured in a closed-loop gain of +2V/V to accommodate the input voltage range, V<sub>OUT</sub> = 4V<sub>P-P</sub>.

**Note 6:** Lowpass-filter bandwidth is 22kHz for f = 1kHz and 80kHz for f = 20kHz. Noise floor of test equipment =  $10nV/\sqrt{Hz}$ .

### **Typical Operating Characteristics**

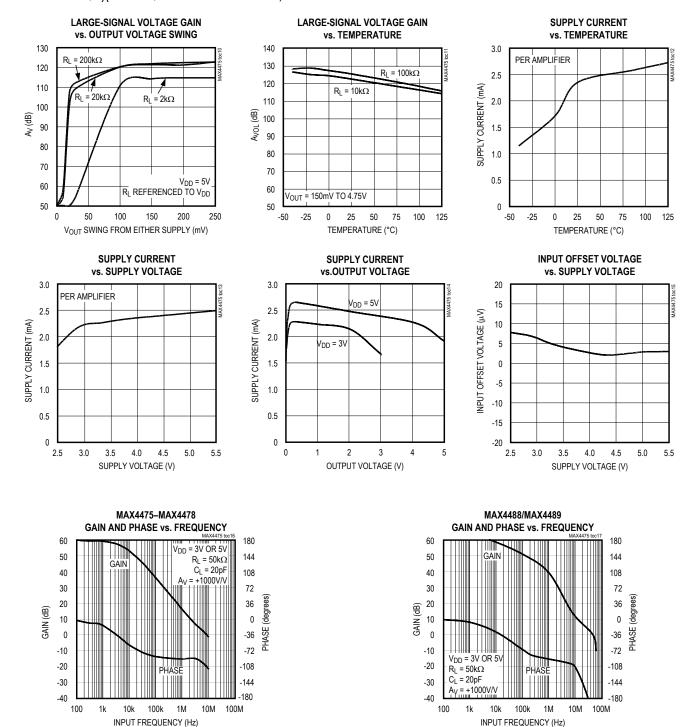
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# SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

### **Typical Operating Characteristics (continued)**

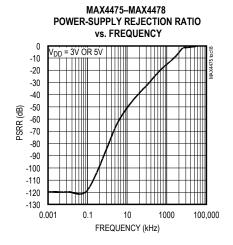
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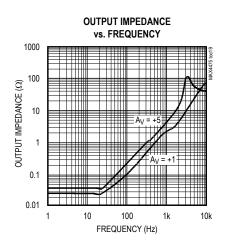


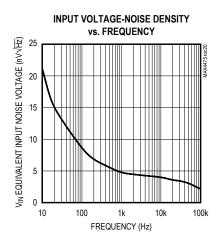
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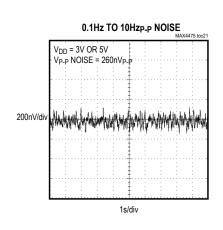
### **Typical Operating Characteristics (continued)**

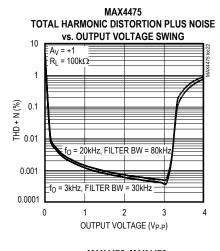
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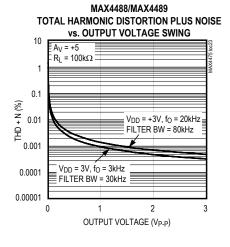


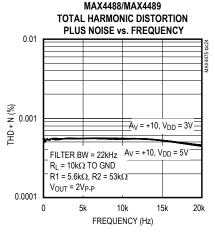


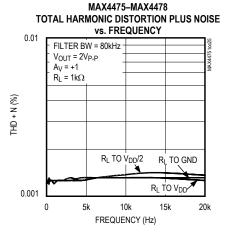








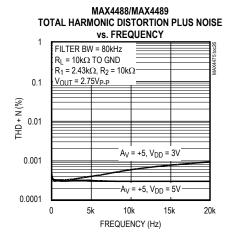


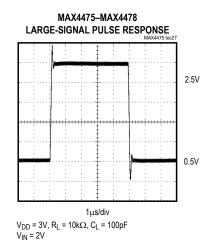


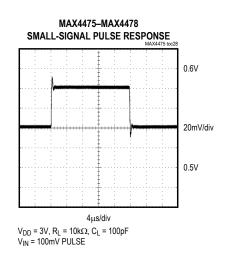
## SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

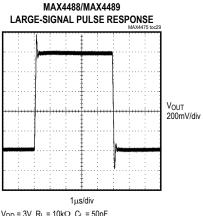
### **Typical Operating Characteristics (continued)**

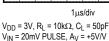
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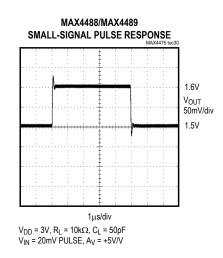


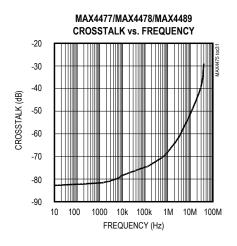












# SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

## **Pin Description**

		PIN				
MAX4475/ MAX4488	MAX4475/ MAX4488	MAX4476	MAX4477/ MAX4489	MAX4478	NAME	FUNCTION
SOT23/TDFN	SO/µMAX	SOT23/TDFN	SO/μMAX	SO/TSSOP		
1	6	1	1, 7	1, 7, 8, 14	OUT, OUTA, OUTB, OUTC, OUTD	Amplifier Output
2	4	2	4	11	V <sub>SS</sub>	Negative Supply. Connect to ground for single-supply operation
3	3	3	3, 5	3, 5, 10, 12	IN+, INA+, INB+, INC+, IND+	Noninverting Amplifier Input
4	2	4	2, 6	2, 6, 9, 13	IN-, INA-, INB-, INC-, IND-	Inverting Amplifier Input
6	7	6	8	4	V <sub>DD</sub>	Positive Supply
5	8	_	_	_	SHDN	Shutdown Input. Connect to V <sub>DD</sub> for normal operation (amplifier(s) enabled).
_	1, 5	5	_	_	N.C.	No Connection. Not internally connected.
EP	_	EP	_	_	EP	Exposed Paddle (TDFN Only). Connect to V <sub>SS</sub> .

## SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

### **Detailed Description**

The MAX4475–MAX4478/MAX4488/MAX4489 single-supply operational amplifiers feature ultra-low noise and distortion. Their low distortion and low noise make them ideal for use as preamplifiers in wide dynamic-range applications, such as 16-bit analog-to-digital converters (see *Typical Operating Circuit*). Their high-input impedance and low noise are also useful for signal conditioning of high-impedance sources, such as piezoelectric transducers.

These devices have true rail-to-rail output operation, drive loads as low as  $1k\Omega$  while maintaining DC accuracy, and can drive capacitive loads up to 200pF without oscillation. The input common-mode voltage range extends from (VDD - 1.6V) to 200mV below the negative rail. The pushpull output stage maintains excellent DC characteristics, while delivering up to  $\pm 5$ mA of current.

The MAX4475–MAX4478 are unity-gain stable, while the MAX4488/MAX4489 have a higher slew rate and are stable for gains  $\geq$  5V/V. The MAX4475/MAX4488 feature a low-power shutdown mode, which reduces the supply current to 0.01µA and disables the outputs.

### **Low Distortion**

Many factors can affect the noise and distortion that the device contributes to the input signal. The following guidelines offer valuable information on the impact of design choices on Total Harmonic Distortion (THD).

Choosing proper feedback and gain resistor values for a particular application can be a very important factor in reducing THD. In general, the smaller the closed-loop gain, the smaller the THD generated, especially when driving heavy resistive loads. The THD of the part normally increases at approximately 20dB per decade, as a function of frequency. Operating the device near or above the full-power bandwidth significantly degrades distortion.

Referencing the load to either supply also improves the part's distortion performance, because only one of the MOSFETs of the push-pull output stage drives the output. Referencing the load to midsupply increases the part's distortion for a given load and feedback setting. (See the Total Harmonic Distortion vs. Frequency graph in the *Typical Operating Characteristics*.)

For gains ≥ 5V/V, the decompensated devices MAX4488/ MAX4489 deliver the best distortion performance, since they have a higher slew rate and provide a higher amount of loop gain for a given closed-loop gain setting. Capacitive loads below 100pF do not significantly affect distortion results. Distortion performance is relatively constant over supply voltages.

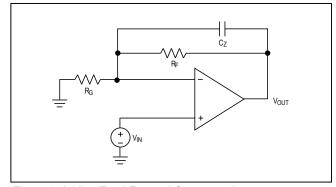


Figure 1. Adding Feed-Forward Compensation

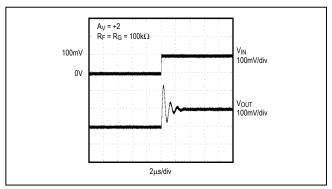


Figure 2a. Pulse Response with No Feed-Forward Compensation

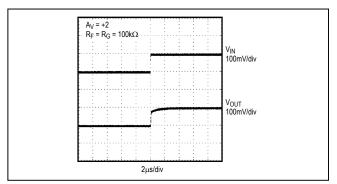


Figure 2b. Pulse Response with 10pF Feed-Forward Compensation

## SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

#### **Low Noise**

The amplifier's input-referred noise-voltage density is dominated by flicker noise at lower frequencies, and by thermal noise at higher frequencies. Because the thermal noise contribution is affected by the parallel combination of the feedback resistive network ( $R_F \parallel R_G$ , Figure 1), these resistors should be reduced in cases where the system bandwidth is large and thermal noise is dominant. This noise contribution factor decreases, however, with increasing gain settings.

For example, the input noise-voltage density of the circuit with  $R_F=100k\Omega,\ R_G=11k\Omega$  (A<sub>V</sub> = +5V/V) is  $e_n=14nV/\sqrt{Hz},\ e_n$  can be reduced to 6nV/ $\sqrt{Hz}$  by choosing  $R_F=10k\Omega,\ R_G=1.1k\Omega$  (A<sub>V</sub> = +5V/V), at the expense of greater current consumption and potentially higher distortion. For a gain of 100V/V with  $R_F=100k\Omega,\ R_G=1.1k\Omega,$  the  $e_n$  is still a low 6nV/ $\sqrt{Hz}$ .

## Using a Feed-Forward Compensation Capacitor, CZ

The amplifier's input capacitance is 10pF. If the resistance seen by the inverting input is large (feedback network), this can introduce a pole within the amplifier's bandwidth resulting in reduced phase margin. Compensate the reduced phase margin by introducing a feed-forward capacitor ( $C_Z$ ) between the inverting input and the output (Figure 1). This effectively cancels the pole from the inverting input of the amplifier. Choose the value of  $C_Z$  as follows:

$$C_Z = 10 \times (R_F / R_G) [pF]$$

In the unity-gain stable MAX4475–MAX4478, the use of a proper  $C_Z$  is most important for  $A_V$  = +2V/V, and  $A_V$  = -1V/V. In the decompensated MAX4488/MAX4489,  $C_Z$  is most important for  $A_V$  = +10V/V. Figures 2a and 2b show transient response both with and without  $C_Z$ .

Using a slightly smaller  $C_Z$  than suggested by the formula above achieves a higher bandwidth at the expense of reduced phase and gain margin. As a general guideline, consider using  $C_Z$  for cases where  $R_G \parallel R_F$  is greater than  $20k\Omega$  (MAX4475–MAX4478) or greater than  $5k\Omega$  (MAX4488/MAX4489).

## **Applications Information**

The MAX4475–MAX4478/MAX4488/MAX4489 combine good driving capability with ground-sensing input and rail-to-rail output operation. With their low distortion and low noise, they are ideal for use in ADC buffers, medical instrumentation systems and other noise-sensitive applications.

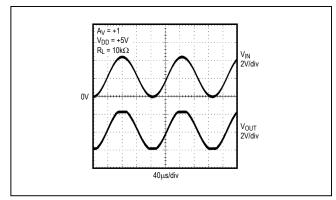


Figure 3. Overdriven Input Showing No Phase Reversal

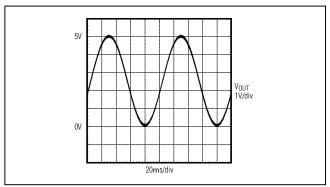


Figure 4. Rail-to-Rail Output Operation

### Ground-Sensing and Rail-to-Rail Outputs

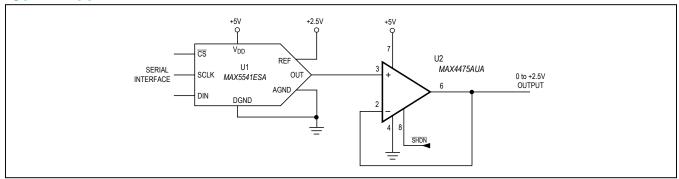
The common-mode input range of these devices extends below ground, and offers excellent common-mode rejection. These devices are guaranteed not to undergo phase reversal when the input is overdriven (Figure 3).

Figure 4 showcases the true rail-to-rail output operation of the amplifier, configured with  $A_V = 5 \text{V/V}$ . The output swings to within 8mV of the supplies with a  $10 \text{k}\Omega$  load, making the devices ideal in low-supply voltage applications

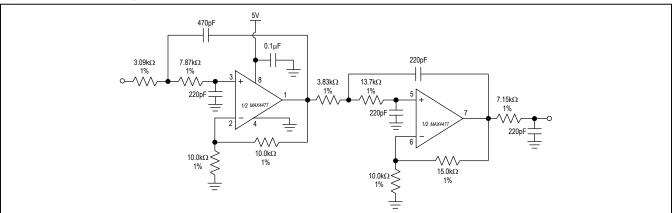
### **Power Supplies and Layout**

The MAX4475–MAX4478/MAX4488/MAX4489 operate from a single +2.7V to +5.5V power supply or from dual supplies of  $\pm 1.35$ V to  $\pm 2.75$ V. For single-supply operation, bypass the power supply with a  $0.1\mu$ F ceramic

### **Typical Application Circuit**



### **Typical Operating Circuit**



capacitor placed close to the  $V_{DD}$  pin. If operating from dual supplies, bypass each supply to ground.

Good layout improves performance by decreasing the amount of stray capacitance and noise at the op amp's inputs and output. To decrease stray capacitance, minimize PC board trace lengths and resistor leads, and place external components close to the op amp's pins.

### **Typical Application Circuit**

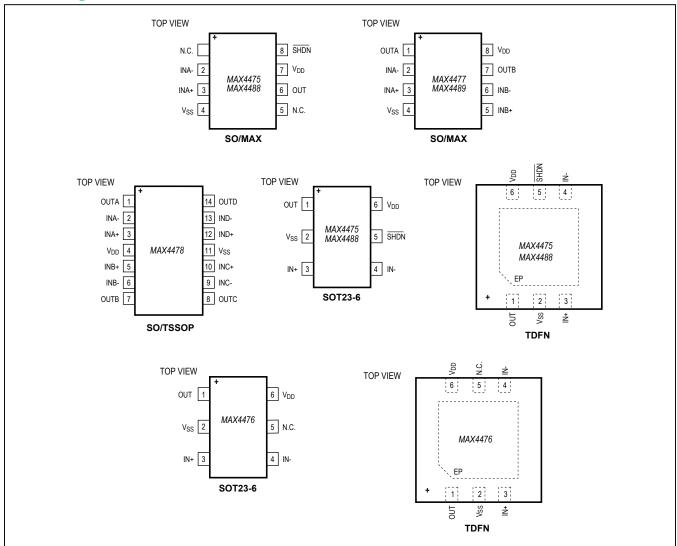
The Typical Application Circuit shows the single MAX4475 configured as an output buffer for the MAX5541 16-bit DAC. Because the MAX5541 has an unbuffered voltage output, the input bias current of the op amp used must be less than 6nA to maintain 16-bit accuracy. The MAX4475 has an input bias current of only 150pA (max), virtually eliminating this as a source

of error. In addition, the MAX4475 has excellent open-loop gain and common-mode rejection, making this an excellent output buffer amplifier.

### **DC-Accurate Lowpass Filter**

The MAX4475–MAX4478/MAX4488/MAX4489 offer a unique combination of low noise, wide bandwidth, and high gain, making them an excellent choice for active filters up to 1MHz. The *Typical Operating Circuit* shows the dual MAX4477 configured as a 5th order Chebyschev filter with a cutoff frequency of 100kHz. The circuit is implemented in the Sallen-Key topology, making this a DC-accurate filter.

## **Pin Configurations**



## SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

## **Ordering Information**

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4475AUT+T	-40°C to +125°C	6 SOT23	AAZV
MAX4475AUA+	-40°C to +125°C	8 µMAX	_
MAX4475ASA+	-40°C to +125°C	8 SO	_
MAX4475ATT+T	-40°C to +125°C	6 TDFN-EP*	+ADD
MAX4475AUT/V+T	-40°C to +125°C	6 SOT23	+ACQQ
MAX4476AUT+T	-40°C to +125°C	6 SOT23	AAZX
MAX4476ATT+T	-40°C to +125°C	6 TDFN-EP*	+ADF
<b>MAX4477</b> AUA+	-40°C to +125°C	8 µMAX	_
MAX4477AUA+	-40°C to +125°C	8 µMAX	_
MAX4477AUA/V+T	-40°C to +125°C	8 µMAX	+AA/V
MAX4477ASA+	-40°C to +125°C	8 SO	_
MAX4478AUD+	-40°C to +125°C	14 TSSOP	_
MAX4478AUD/V+	-40°C to +125°C	14 TSSOP	_
MAX4478ASD+	-40°C to +125°C	14 SO	_
MAX4488AUT+T	-40°C to +125°C	6 SOT23	AAZW
MAX4488AUA+	-40°C to +125°C	8 µMAX	_
MAX4488ASA+	-40°C to +125°C	8 SO	
MAX4488ATT+T	-40°C to +125°C	6 TDFN-EP*	+ADE
MAX4489AUA+	-40°C to +125°C	8 µMAX	_
MAX4489AUA/V+T	-40°C to +125°C	8 µMAX	
MAX4489ASA+	-40°C to +125°C	8 SO	_

<sup>+</sup>Denotes a lead(Pb)-free/RoHS-compliant package.

## **Chip Information**

PROCESS: BICMOS

### **Selector Guide**

PART	GAIN BW (MHz)	STABLE GAIN (V/V)	NO. OF AMPS	SHDN
MAX4475	10	1	1	Yes
MAX4476	10	1	1	_
MAX4477	10	1	2	_
MAX4478	10	1	4	_
MAX4488	42	5	1	Yes
MAX4489	42	5	2	_

<sup>\*</sup>EP = Exposed pad (connect to  $V_{SS}$ ). /V denotes an automotive qualified part.

T = Tape and reel.

## SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
4	12/09	Added lead-free designations and an automotive part to the Ordering Information and added input current spec in Absolute Maximum Ratings section	1, 2, 13
5	7/10	Added /V designation to the MAX4475 product and soldering temperature	1, 2
6	6/12	Added /V designation for MAX4489.	13
7	1/18	Added AEC statement to Features section	1
8	7/18	Updated Ordering Information table	14
9	7/18	Updated Absolute Maximum Rating and Package Information	2, 14
10	8/18	Updated Package Information section	2–4
11	4/19	Updated General Description and Ordering Information section	1, 16

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